

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	583245	capacitor	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/11 16:23
2	BRS	L2	166	low adj temperature adj dielectric	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/11 16:23
3	BRS	L4	133168	(aluminum adj oxide) or AlO or (aluminum adj nitride) or AlN	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/11 16:24
4	BRS	L5	12	1 and 2 and 4	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/11 17:13
5	BRS	L6	46	1 and 2	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/11 17:41

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	46	capacitor and (low adj temperature adj dielectric)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/12 13:35
2	BRS	L2	2154	(low adj temperature) near4 dielectric	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/12 13:36
3	BRS	L3	55599	(aluminum adj nitride) or AlN or (aluminium adj oxide) or AlO	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/12 13:37
4	BRS	L4	51	2 and 3 and capacitor	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/12 13:45
5	BRS	L5	382	expos\$6 near4 (Al or aluminum) near6 (oxygen or nitrogen)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/12 13:48

	Type	L #	Hits	Search Text	DBs	Time Stamp
6	BRS	L6	293	5 and temperature	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/12 13:48
7	BRS	L7	29	6 and capacitor	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/12 13:50
8	BRS	L8	16	7 and (@ad<20010105)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/12 14:00
9	IS&R	L9	4117	(438/396).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/12 14:01
10	IS&R	L10	803	(438/239).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/12 14:01

	Type	L #	Hits	Search Text	DBs	Time Stamp
11	BRS	L11	26	9 and 2	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/12 14:07
12	BRS	L12	9	10 and 2	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2004/08/12 14:07